



IN THE UNITED STATES PATENT AND TRADEMARK

OFFICE

In re the Application of: **YAMAUCHI, Tsunenori**

Group Art Unit: 2812

Patent No.: 6,838,349

10/053712

Examiner: C. W. Lattin

Issued: **January 4, 2005**

P.T.O. Confirmation No.: 4240

For. **SEMICONDUCTOR DEVICE AND METHOD FOR FABRICATING THE SAME**

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.501

Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

March 22, 2005

Sir:

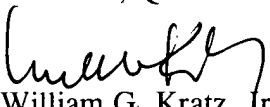
Submitted herewith is a copy of a search report in a European counterpart application dated October 21, 2004 and the cited references.

The cited documents are believed to be pertinent due to citation in the counterpart application. Please place such documents in the file of the above-captioned patent.

In the event any fees are due in connection with this paper, please charge our Deposit Account 01-2340.

Respectfully submitted,

ARMSTRONG, KRATZ, QUINTOS, HANSON & BROOKS, LLP

  
William G. Kratz, Jr.  
Attorney for Applicant  
Reg. No. 22,631

WGK/nrp  
Atty. Docket No. 020076  
Suite 1000, 1725 K Street, N.W.  
Washington, D.C. 20006  
(202) 659-2930



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Enclosures: Information Disclosure Statement PTO-1449  
Search Report in European counterpart application dated 10/21/04  
References (11)



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 Search Report in European counterpart application dated 10/21/04  
 References (11)

<b>INFORMATION DISCLOSURE CITATION PTO-1449</b>	Atty. Docket No. <b>020076</b>	Patent No. <b>6,838,349</b>
	Applicant(s): <b>YAMAUCHI, Tsunenori</b>	
	Issued: <b>January 4, 2005</b>	Group Art Unit: <b>2812</b>

#### U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
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_____	AB						
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P.B.5818 - Patentlaan 2  
2280 HV Rijswijk (ZH)  
☎ +31 70 340 2040  
TX 31651 epo nl  
FAX +31 70 340 3016

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Fenlon, Christine Lesley  
Haseltine Lake,  
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15-19 Kingsway  
London WC2B 6UD  
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ACKNOWLEDGEMENT
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Zeichen/Ref./Réf.

P81120EP00/MR

Anmeldung Nr./Application No./Demande n°./Patent Nr./Patent No./Brevet n°.

02250610.9-2203-

Anmelder/Applicant/Demandeur/Patentinhaber/Propriétaire/Titulaire

FUJITSU LIMITED

## COMMUNICATION

The European Patent Office herewith transmits as an enclosure the European search report for the above-mentioned European patent application.

If applicable, copies of the documents cited in the European search report are attached.

☐ Additional set(s) of copies of the documents cited in the European search report is (are) enclosed as well

The following specifications given by the applicant have been approved by the Search Division:

☒ abstract

☐ title

☐ The abstract was modified by the Search Division and the definitive text is attached to this communication.

The following figure will be published together with the abstract:

1

COMMUNICATION

21 OCT 2004

## REFUND OF THE SEARCH FEE

If applicable under Article 10 Rules relating to fees, a separate communication from the Receiving Section on the refund of the search fee will be sent later.



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Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.Cl.7)
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Place of search Munich		Date of completion of the search 13 October 2004	Examiner Berthold, K
CATEGORY OF CITED DOCUMENTS X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document			

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The present search report has been drawn up for all claims			
Place of search Munich		Date of completion of the search 13 October 2004	Examiner Berthold, K
<b>CATEGORY OF CITED DOCUMENTS</b> X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document			

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**ANNEX TO THE EUROPEAN SEARCH REPORT  
ON EUROPEAN PATENT APPLICATION NO.**

EP 02 25 0610

This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report.  
The members are as contained in the European Patent Office EDP file on  
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13-10-2004

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